## **PNP General Purpose Amplifier**

(continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
	RACTERISTICS Collector-Emitter Breakdown	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	40		V
/ <sub>(BR)CBO</sub>	Voltage* Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu \text{A}, I_{\rm E} = 0$	60		V
(BR)CBO	Emitter-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu \text{A}, I_{\rm E} = 0$ $I_{\rm E} = 10 \ \mu \text{A}, I_{\rm C} = 0$	5.0		V
EBO	Emitter Cutoff Current	$V_{EB} = 30 V$	5.0	50	nA
CBO	Collector Cutoff Current	$V_{\text{CB}} = 30 \text{ V}$		50	nA
BO		VCB - 00 V		00	10.0
	Collector-Emitter Saturation		100 30 50	300 0.4	V
		$I_{C} = 300 \text{ mA}, V_{CE} = 10 \text{ V}$			
CE(sat)	Collector-Emitter Saturation Voltage*	$I_{\rm C} = 150 \text{ mA}, I_{\rm B} = 15 \text{ mA}$			V V
		$I_{\rm C} = 300 \text{ mA}, I_{\rm B} = 30 \text{ mA}$		1.6	
	Base-Emitter Saturation Voltage	$I_{C} = 300 \text{ mA}, I_{B} = 30 \text{ mA}$ $I_{C} = 150 \text{ mA}, I_{B} = 15 \text{ mA}^{*}$ $I_{C} = 300 \text{ mA}, I_{B} = 30 \text{ mA}$		1.6 1.3 2.6	
ulse Test: Pulse	Base-Emitter Saturation Voltage	I <sub>C</sub> = 150 mA, I <sub>B</sub> = 15 mA* I <sub>C</sub> = 300 mA, I <sub>B</sub> = 30 mA	Emitter S	1.3 2.6	VVV
Туріса	Base-Emitter Saturation Voltage width ≤ 300 µs, Duty Cycle ≤ 2.0%	$I_{C} = 150 \text{ mA}, I_{B} = 15 \text{ mA}^{*}$ $I_{C} = 300 \text{ mA}, I_{B} = 30 \text{ mA}$		1.3 2.6	VVV

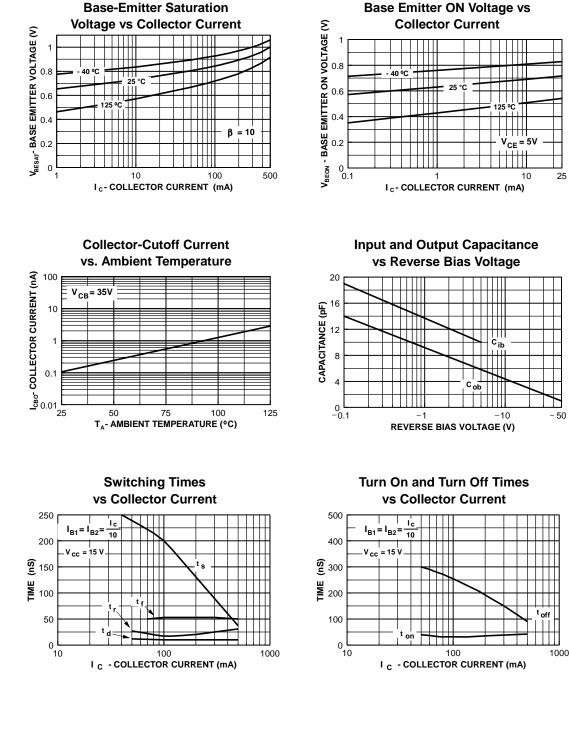
## Spice Model

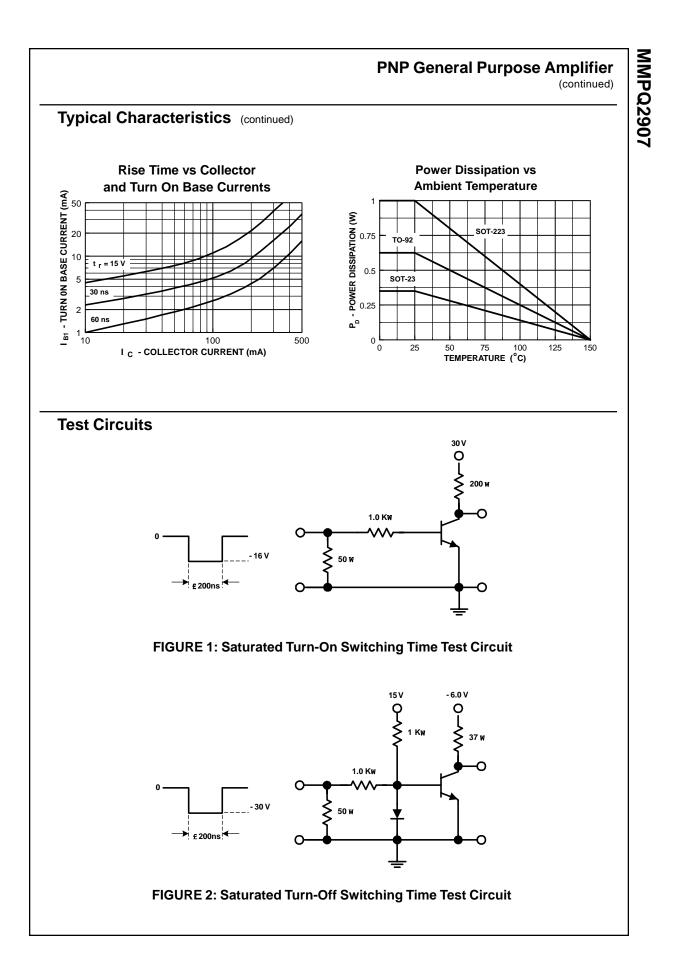
PNP (Is=650.6E-18 Xti=3 Eg=1.11 Vaf=115.7 Bf=231.7 Ne=1.829 Ise=54.81f Ikf=1.079 Xtb=1.5 Br=3.563 Nc=2 Isc=0 Ikr=0 Rc=.715 Cjc=14.76p Mjc=.5383 Vjc=.75 Fc=.5 Cje=19.82p Mje=.3357 Vje=.75 Tr=111.3n Tf=603.7p Itf=.65 Vtf=5 Xtf=1.7 Rb=10)

MMPQ2907

**MMPQ2907** 

# PNP General Purpose Amplifier (continued) Typical Characteristics (continued) Base-Emitter Saturation Voltage vs Collector Current Voltage vs Collector Current United State St





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